

PC733

AC Input Type **Photocoupler**

* Lead forming type (I type) is also available. (PC733I) (page 656)

■ Features

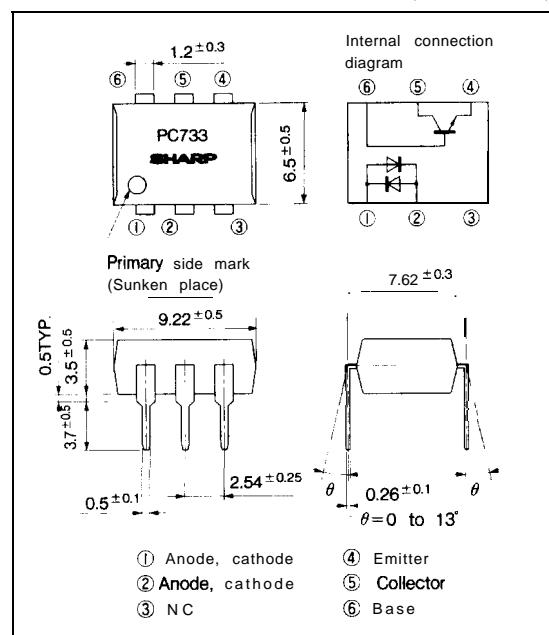
1. AC input response
2. High isolation voltage between input and output (V_{IS} : 5 000V_{rms})
3. Current transfer ratio
CTR : MIN. 15% at IF= ± 1 mA, V_{CE}=5V
4. Low collector dark current
(I_{CEO} : MAX. 10⁻⁷A at V_{CE}= 20V)
5. TTL compatible output
6. Recognized by UL, file No. E64380

■ Applications

1. Telephone sets
2. Programmable controllers
3. System appliances, measuring instruments
4. Signal transmission between circuits of different potentials and impedances

■ Outline Dimensions

(Unit : mm)



■ Absolute Maximum Ratings

(Ta = 25°C)

Parameter	Symbol	Rating	Unit	
Input	Forward current	I _F	±50	mA
	*1 Peak forward current	I _{FM}	±1	A
	Power dissipation	P	70	mW
output	Collector -emitter voltage	V _{CEO}	35	v
	Emitter-collector voltage	V _{ECO}	6	v
	Collector -base voltage	V _{CBO}	35	v
	Emitter -base voltage	V _{EBO}	6	v
	Collector current	I _C	50	mA
	Collector power dissipation	P _C	150	mW
Total power dissipation		P _{tot}	170	mW
*1 Isolation voltage	V _{iso}	5000	Vrms	
Operating temperature	T _{opr}	-25 to +100	°C	
Storage temperature	T _{stg}	-40 to +125	°C	
Soldering temperature	T _{sol}	260	°C	

*1 Pulse width ≤ 100 μs, Duty ratio= 0.001

*2 40 to 60 %RH, AC for 1 minute

*3 For 10 seconds

■ Electro-optical Characteristics

(Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F =±20mA		1.2	1.4	V
	Peak forward voltage	V _{FM}	I _{FM} =±0.5A		—	3.0	V
	Terminal capacitance	C _t	V=0, f=1kHz	—	50	400	pF
output	Collector dark current	I _{CEO}	V _{CE} =20V, I _F =0, R _{BE} =∞			10 ⁻⁷	A
Transfer characteristics	Current transfer ratio	CTR	I _F =±1mA, V _{CE} =5V, R _{BE} =∞	15	—	300	%
	Collector-emitter saturation voltage	V _{CE(sat)}	I _F =±20mA, I _C =1mA, R _{RE} =∞	—	0.1	0.2	V
	Isolation resistance	R _{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	10 ¹¹	—	Ω
	Floating capacitance	C _f	V=0, f=1MHz	—	0.6	1.0	pF
	Cut-off frequency	f _c	V _{CE} =5V, I _C =2mA, R _L =100Ω, R _{BE} =∞, -3dB	15	80	—	kHz
	Response time	t _r	V _{CE} =2V, I _C =2mA	—	4	18	μs
	Fall time	t _f	R _L =100Ω, R _{BE} =∞		3	18	μs

Fig. 1 Forward Current vs. Ambient Temperature

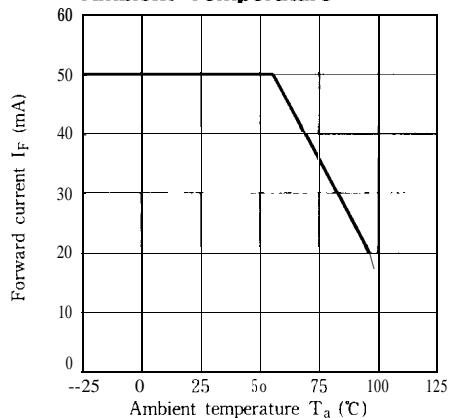


Fig. 2 Diode Power Dissipation v.s. Ambient Temperature

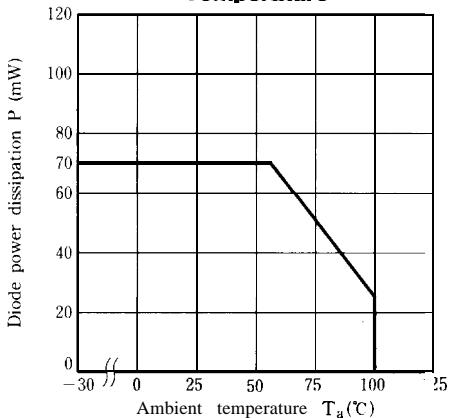


Fig. 3 Collector Power Dissipation VS. Ambient Temperature

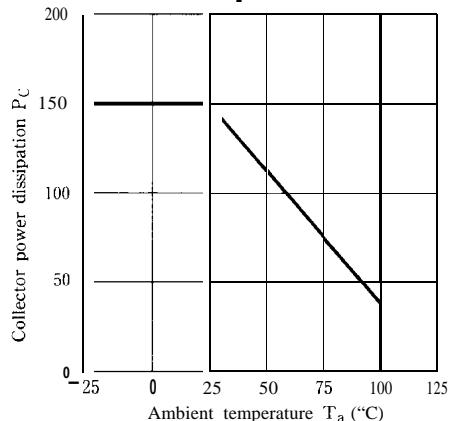


Fig. 4 Power Dissipation vs. Ambient Temperature

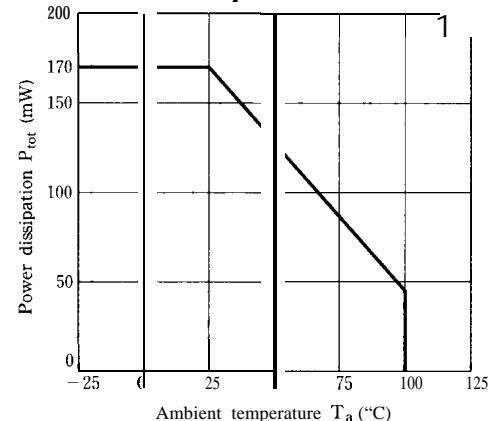
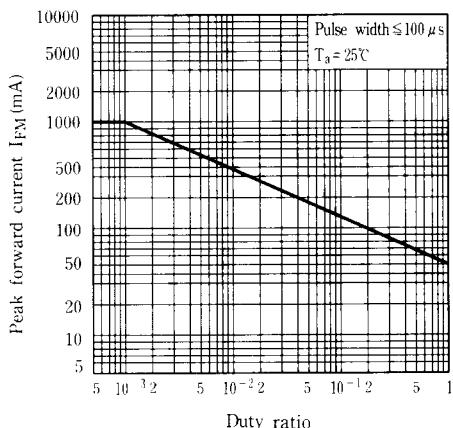
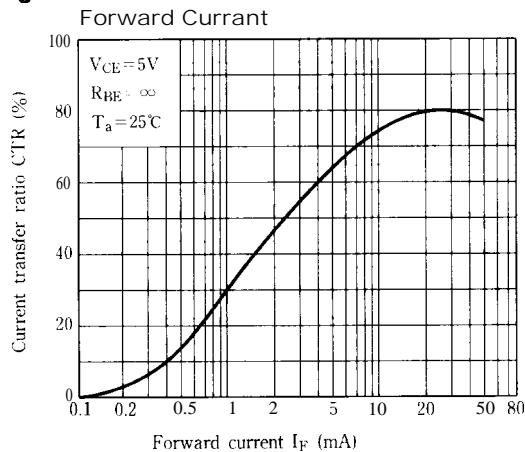
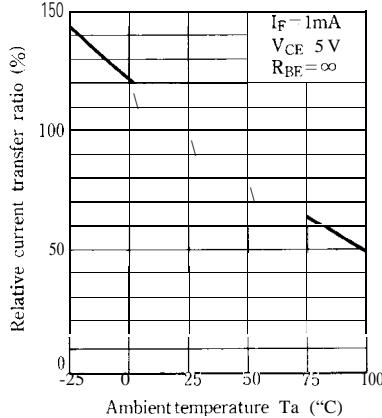
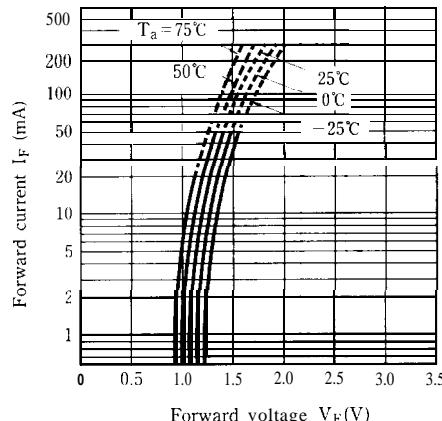
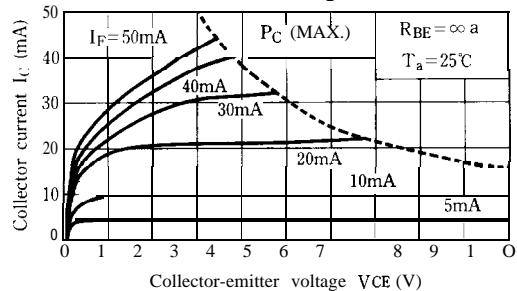


Fig. 5 Peak Forward Current vs. Duty Ratio**Fig. 7 Current Transfer Ratio vs. Forward Current****Fig. 9 Relative Current Transfer Ratio vs. Ambient Temperature****Fig. 6 Forward Current vs. Forward Voltage****Fig. 8 Collector Current vs. Collector-emitter Voltage**

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Photocouplers

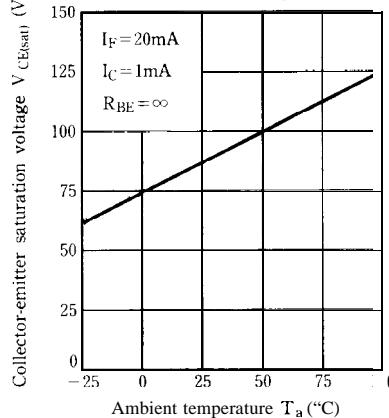
Fig. 10 Collector-emitter Saturation Voltage vs. Ambient Temperature

Fig.11-a Collector Dark Current vs. Ambient Temperature

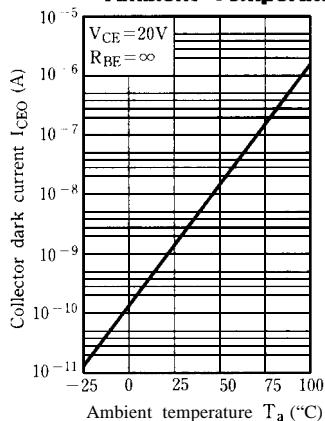


Fig.11-b Collector-base Dark Current vs. Ambient Temperature

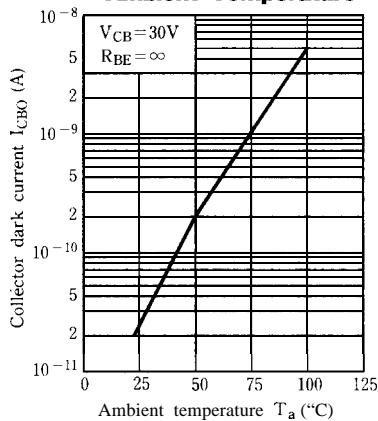


Fig.12 Response Time vs. Load Resistance

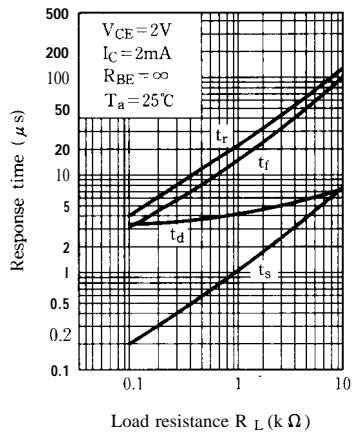
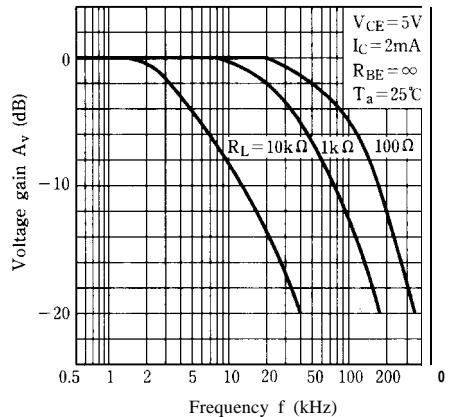
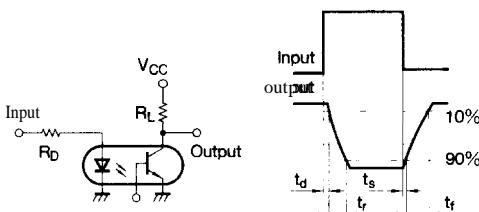


Fig.13 Frequency Response



Test Circuit for Response Time



Test Circuit for Frequency Response

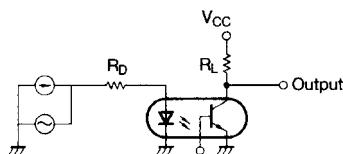
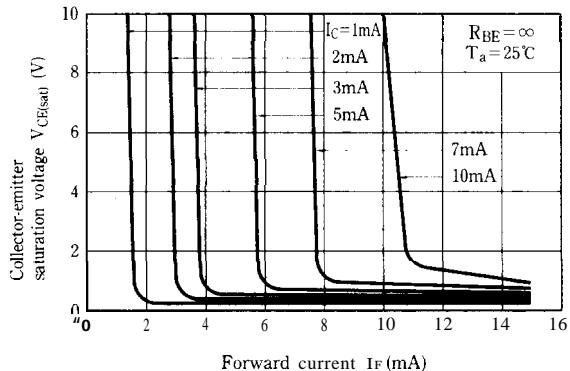


Fig.14 Collector-emitter Saturation Voltage vs. Forward Current



- Please refer to the chapter "Precautions for Use" (Page 78 to 93)